

## ST180C..C SERIES

### PHASE CONTROL THYRISTORS

### Hockey Puk Version

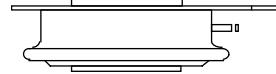
#### Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AB (A-PUK)

350A

#### Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers



case style TO-200AB (A-PUK)

#### Major Ratings and Characteristics

Parameters	ST180C..C	Units
$I_{T(AV)}$	350	A
@ $T_{hs}$	55	°C
$I_{T(RMS)}$	660	A
@ $T_{hs}$	25	°C
$I_{TSM}$	5000	A
@ 60Hz	5230	A
$I^2t$	125	KA <sup>2</sup> s
@ 60Hz	114	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	400 to 2000	V
$t_q$ typical	100	μs
$T_J$	- 40 to 125	°C

## ST180C..C Series

Bulletin I25164 rev. C 02/00

International  
**IR** Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_{J\max}$ mA
ST180C..C	04	400	500	30
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

#### On-state Conduction

Parameter	ST180C..C	Units	Conditions
$I_{T(AV)}$	Max. average on-state current @ Heatsink temperature	A	180° conduction, half sine wave
	55 (85)	°C	double side (single side) cooled
$I_{T(RMS)}$	Max. RMS on-state current	660	@ 25°C heatsink temperature double side cooled
$I_{TSM}$	Max. peak, one-cycle non-repetitive surge current	5000	
		5230	
		4200	
		4400	
$I^2t$	Maximum $I^2t$ for fusing	125	Sinusoidal half wave, Initial $T_J = T_{J\max}$ .
		114	
		88	
		81	
$I^2vt$	Maximum $I^2vt$ for fusing	1250	KA <sup>2</sup> /s t = 0.1 to 10ms, no voltage reapplied
$V_{T(TO)1}$	Low level value of threshold voltage	1.08	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J\max}$ .
$V_{T(TO)2}$	High level value of threshold voltage	1.14	
$r_{t1}$	Low level value of on-state slope resistance	1.18	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J\max}$ .
$r_{t2}$	High level value of on-state slope resistance	1.14	
$V_{TM}$	Max. on-state voltage	1.96	V $I_{pk} = 750A$ , $T_J = T_{J\max}$ , $t_p = 10ms$ sine pulse
$I_H$	Maximum holding current	600	mA $T_J = T_{J\max}$ , anode supply 12V resistive load
$I_L$	Max. (typical) latching current	1000 (300)	

### Switching

Parameter	ST180C..C	Units	Conditions
di/dt	Max. non-repetitive rate of rise of turned-on current	1000	A/ $\mu$ s
t <sub>d</sub>	Typical delay time	1.0	$\mu$ s
t <sub>q</sub>	Typical turn-off time	100	

### Blocking

Parameter	ST180C..C	Units	Conditions
dv/dt	Maximum critical rate of rise of off-state voltage	500	V/ $\mu$ s
I <sub>DRM</sub> I <sub>RRM</sub>	Max. peak reverse and off-state leakage current	30	mA

### Triggering

Parameter	ST180C..C	Units	Conditions
P <sub>GM</sub>	Maximum peak gate power	10	
P <sub>G(AV)</sub>	Maximum average gate power	2.0	W
I <sub>GM</sub>	Max. peak positive gate current	3.0	A
+V <sub>GM</sub>	Maximum peak positive gate voltage	20	V
-V <sub>GM</sub>	Maximum peak negative gate voltage	5.0	
I <sub>GT</sub>	DC gate current required to trigger	TYP. 180 90 40	MAX. - 150 -
V <sub>GT</sub>	DC gate voltage required to trigger	2.9 1.8 1.2	- 3.0 -
I <sub>GD</sub>	DC gate current not to trigger	10	mA
V <sub>GD</sub>	DC gate voltage not to trigger	0.25	V

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### Thermal and Mechanical Specification

Parameter	ST180C..C	Units	Conditions
T <sub>J</sub>	Max. operating temperature range	-40 to 125	°C
T <sub>stg</sub>	Max. storage temperature range	-40 to 150	
R <sub>thJ-hs</sub>	Max. thermal resistance, junction to heatsink	0.17	K/W
		0.08	
R <sub>thC-hs</sub>	Max. thermal resistance, case to heatsink	0.033	K/W
		0.017	
F	Mounting force, ± 10%	4900 (500)	N (Kg)
wt	Approximate weight	50	g
Case style	TO - 200AB (A-PUK)	See Outline Table	

### ΔR<sub>thJ-hs</sub> Conduction

(The following table shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.015	0.015	0.011	0.011	K/W	T <sub>J</sub> = T <sub>J</sub> max.
120°	0.018	0.019	0.019	0.019		
90°	0.024	0.024	0.026	0.026		
60°	0.035	0.035	0.036	0.037		
30°	0.060	0.060	0.060	0.061		

### Ordering Information Table

Device Code		ST 18 0 C 20 C 1							
1	- Thyristor	1	2	3	4	5	6	7	8
2	- Essential part number								
3	- 0 = Converter grade								
4	- C = Ceramic Puk								
5	- Voltage code: Code x 100 = V <sub>RRM</sub> (See Voltage Rating Table)								
6	- C = Puk Case TO-200AB (A-PUK)								
7	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads) 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads) 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads) 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)								
8	- Critical dv/dt: None = 500V/μsec (Standard value) L = 1000V/μsec (Special selection)								

Outline Table

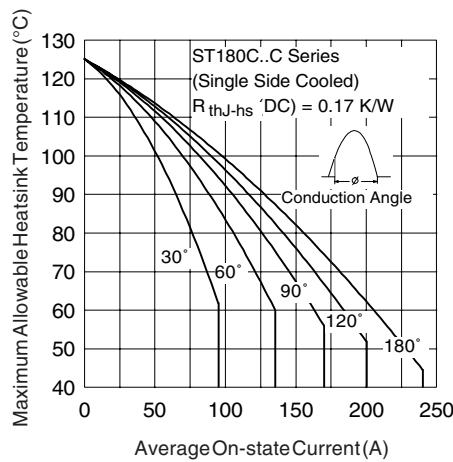
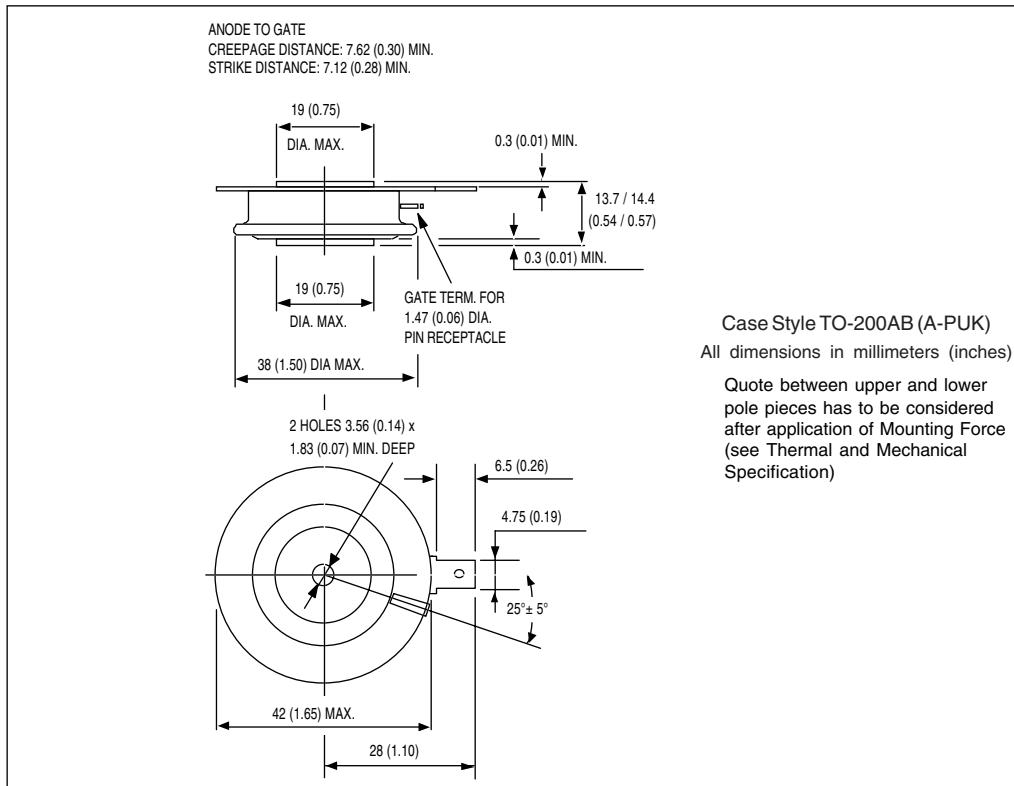


Fig. 1 - Current Ratings Characteristics

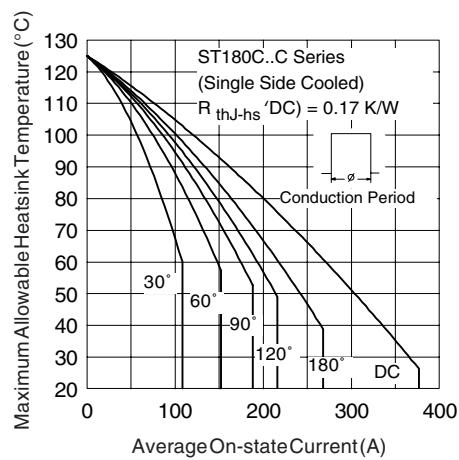


Fig. 2 - Current Ratings Characteristics

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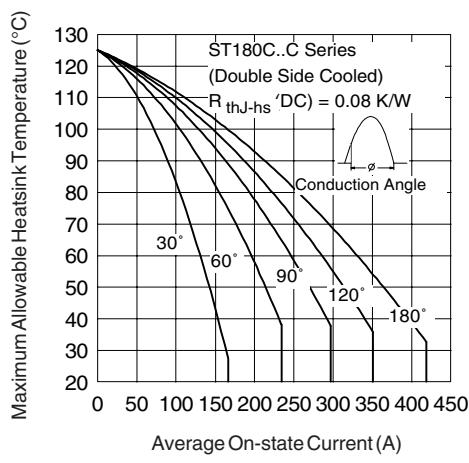


Fig. 3 - Current Ratings Characteristics

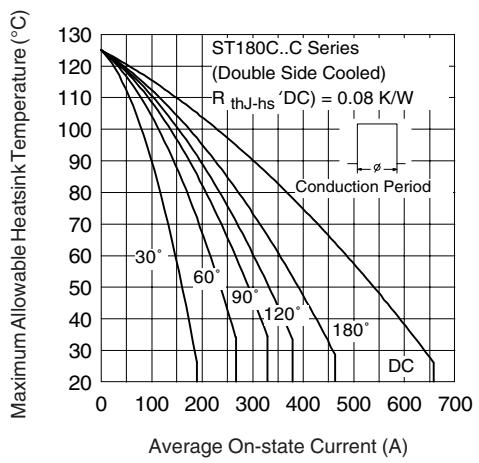


Fig. 4 - Current Ratings Characteristics

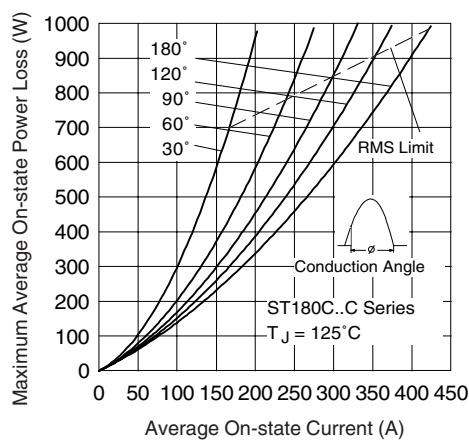


Fig. 5 - On-state Power Loss Characteristics

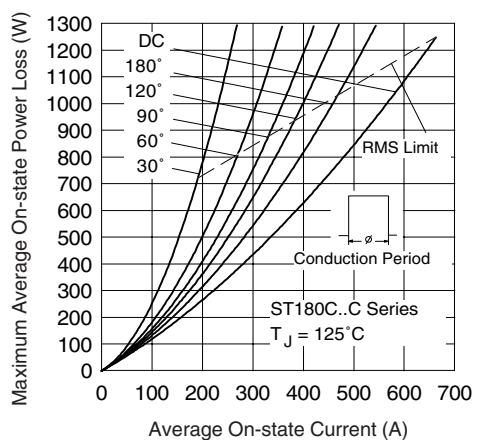


Fig. 6 - On-state Power Loss Characteristics

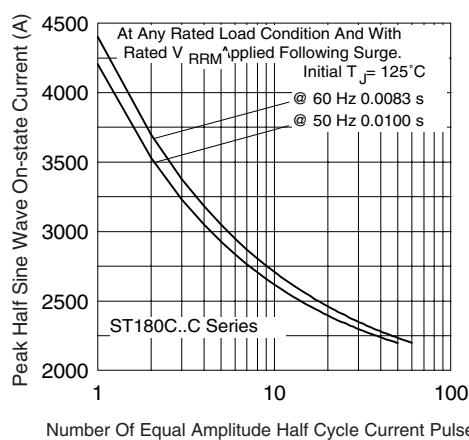


Fig. 7 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

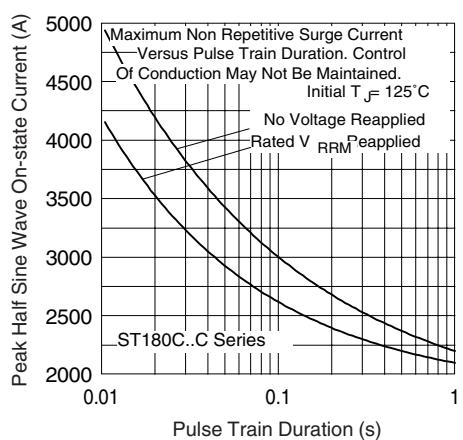


Fig. 8 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

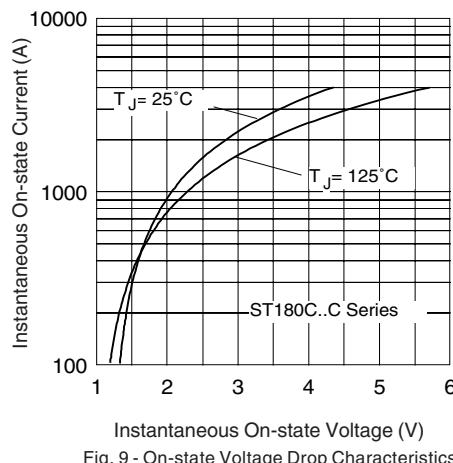


Fig. 9 - On-state Voltage Drop Characteristics

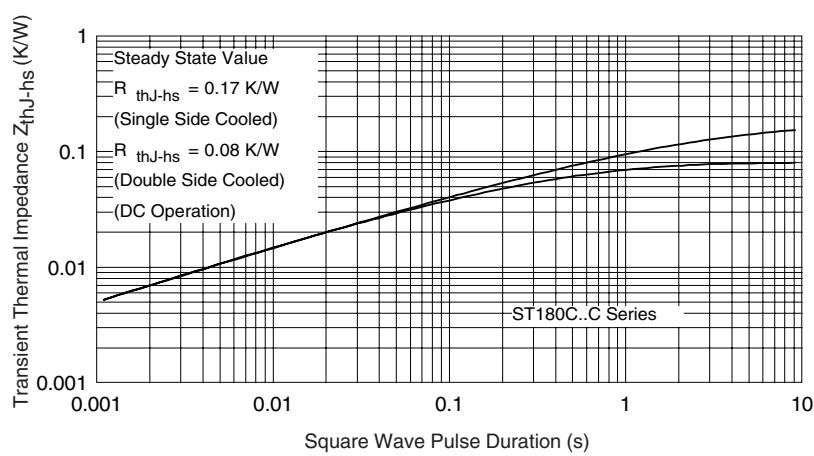


Fig. 10 - Thermal Impedance  $Z_{\text{thJ-hs}}$  Characteristics

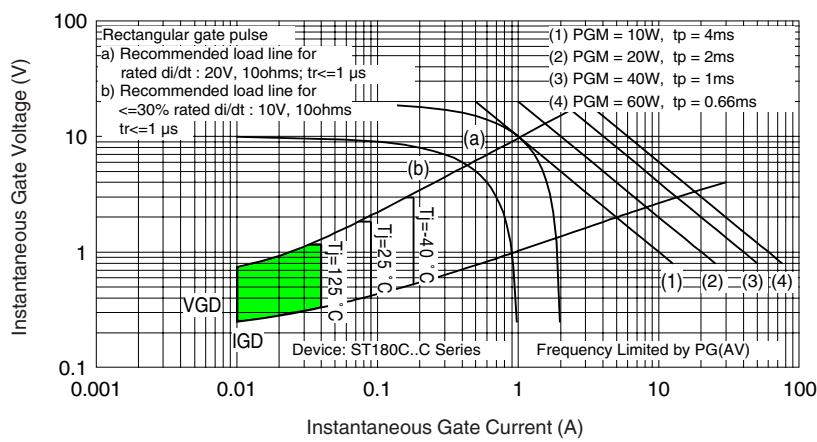


Fig. 11 - Gate Characteristics